

Electronic Supplementary Information (ESI)

Cs₃CuAs₄Q₈ (Q = S, Se): unique two-dimensional layered inorganic thioarsenates with the lowest Cu-to-As ratio and remarkable photocurrent responses

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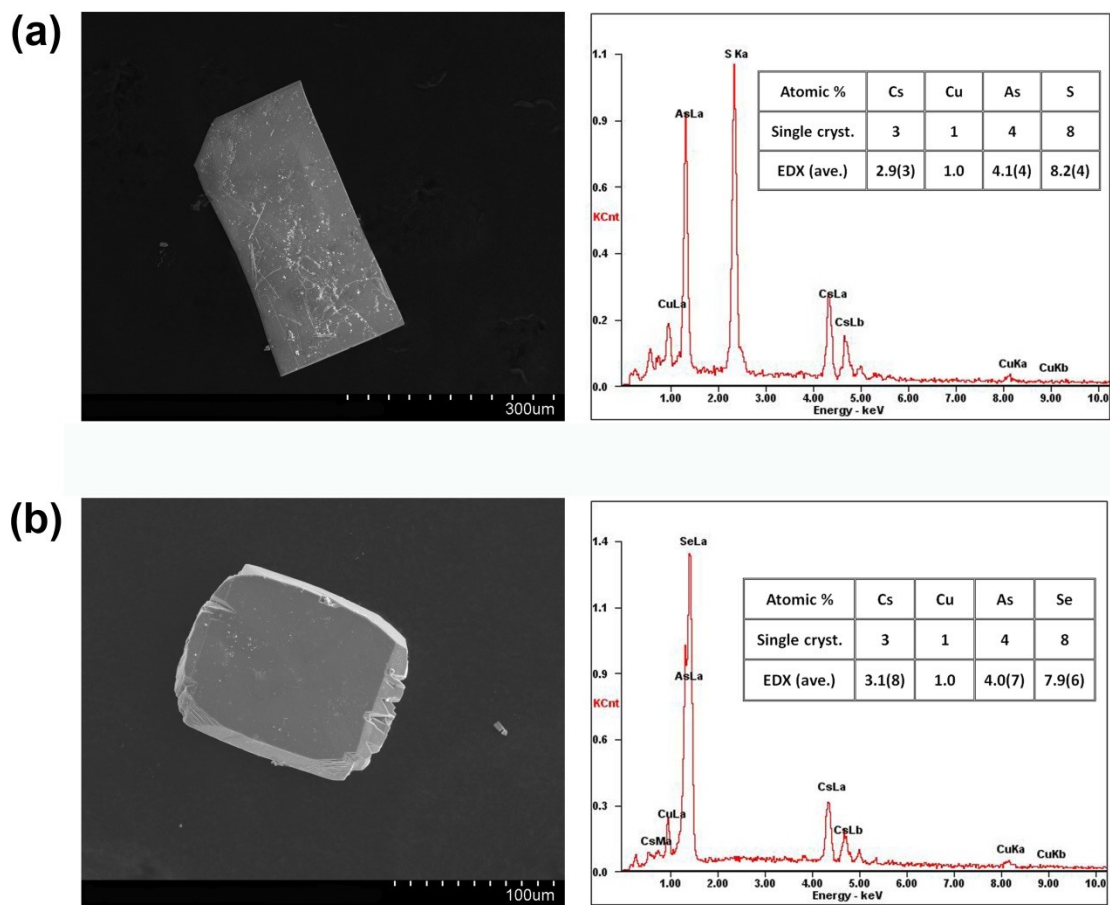


Figure S1. SEM image and energy-dispersive X-ray spectroscopy analysis of (a) $\text{Cs}_3\text{CuAs}_4\text{S}_8$ and (b) $\text{Cs}_3\text{CuAs}_4\text{Se}_8$.

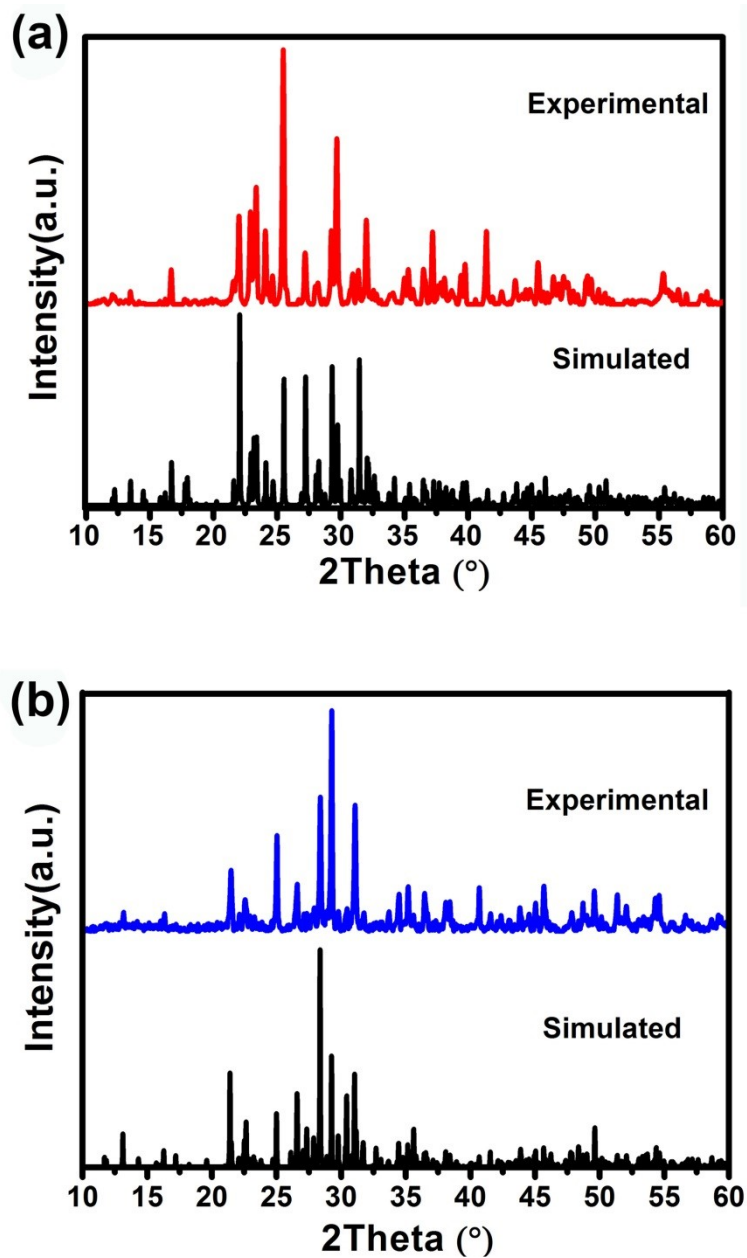


Figure S2. The experimental and simulated powder XRD of of (a) $\text{Cs}_3\text{CuAs}_4\text{S}_8$ and (b) $\text{Cs}_3\text{CuAs}_4\text{Se}_8$.

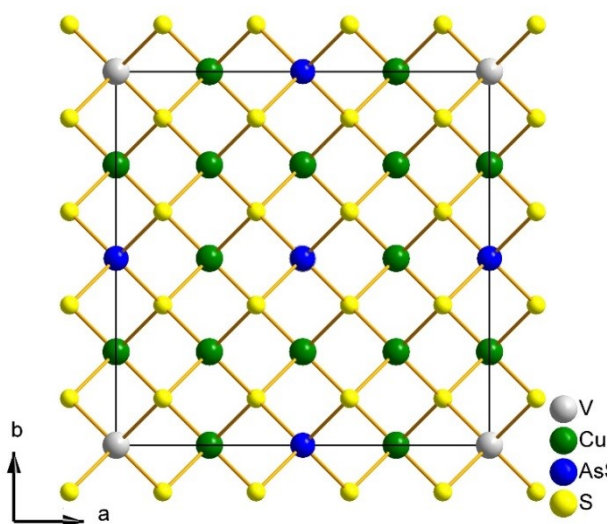


Figure S3. 3D structure of $\text{VCu}_{13}\text{As}_3\text{S}_{16}$ along the c direction.

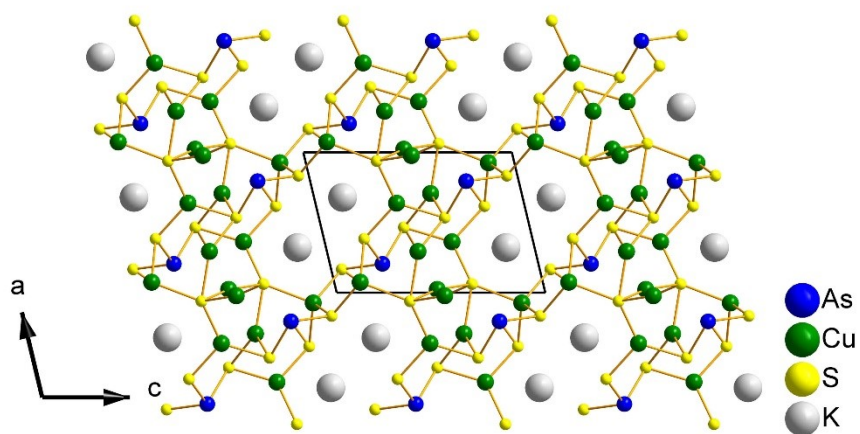


Figure S4. 3D structure of KCu_4AsS_4 along the b direction.

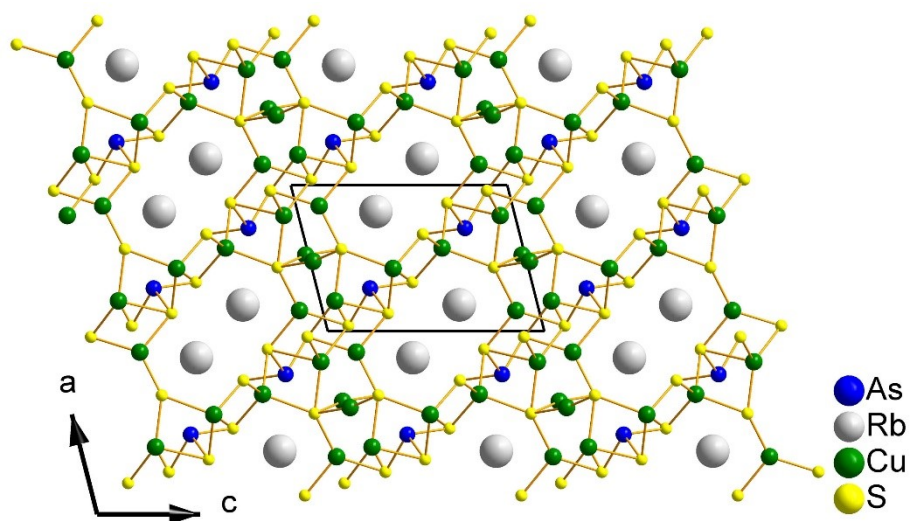


Figure S5. 3D structure of $\text{RbCu}_4\text{AsS}_4$ along the b direction.

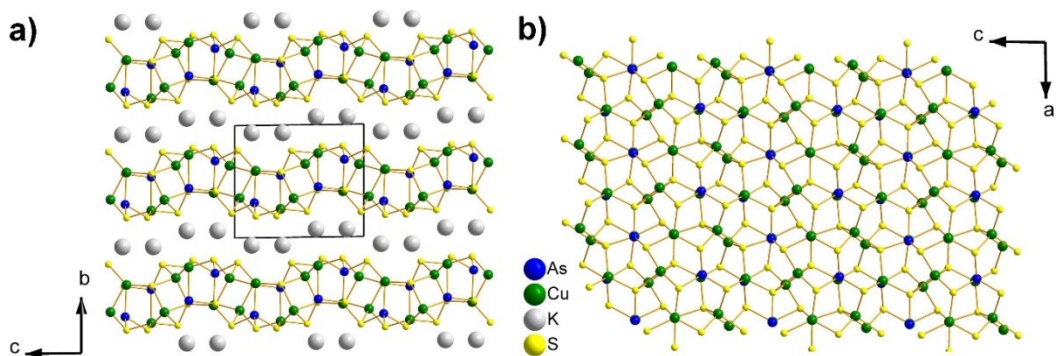


Figure S6. (a) 2D layered structure of KCu_2AsS_3 along the a direction. (b) $[\text{Cu}_2\text{AsS}_3]^-$ layer in the structure.

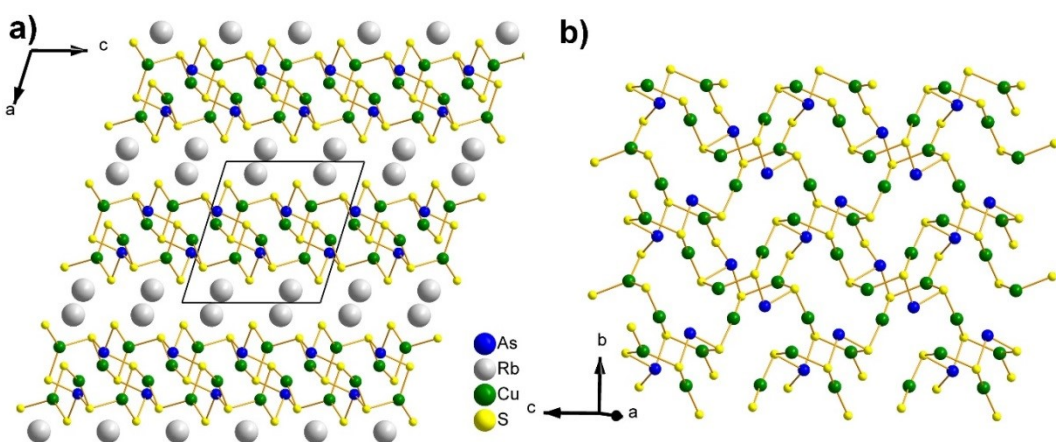


Figure S7. (a) 2D layered structure of $\text{RbCu}_2\text{AsS}_3$ along the b direction. (b) $[\text{Cu}_2\text{AsS}_3]^-$ layer in the structure.

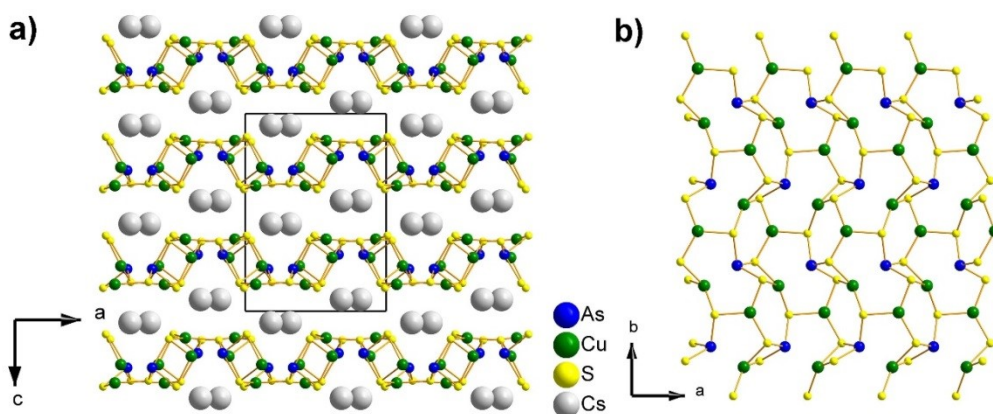


Figure S8. (a) 2D layered structure of $\text{CsCu}_2\text{AsS}_3$ viewed from b direction. (b) $[\text{Cu}_2\text{AsS}_3]^-$ layer along the ab plane.

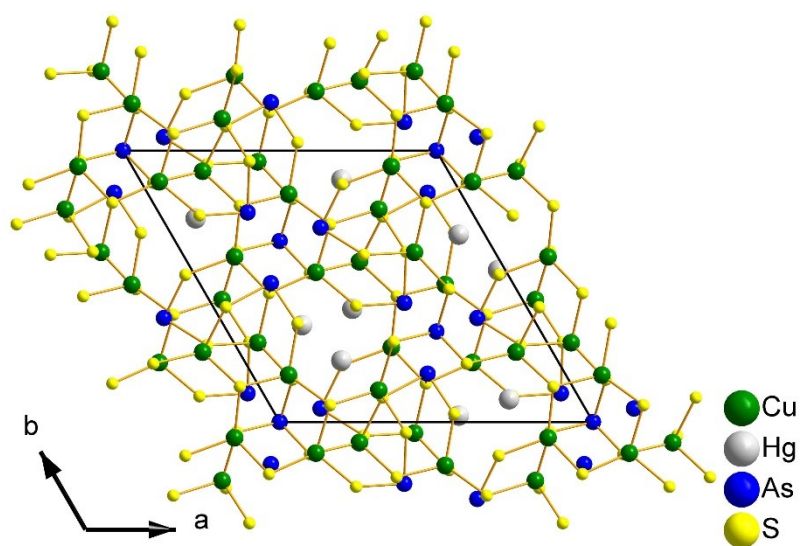


Figure S9. 3D structure of $\text{Hg}_3\text{Cu}_6\text{As}_4\text{S}_{12}$ along the c direction.

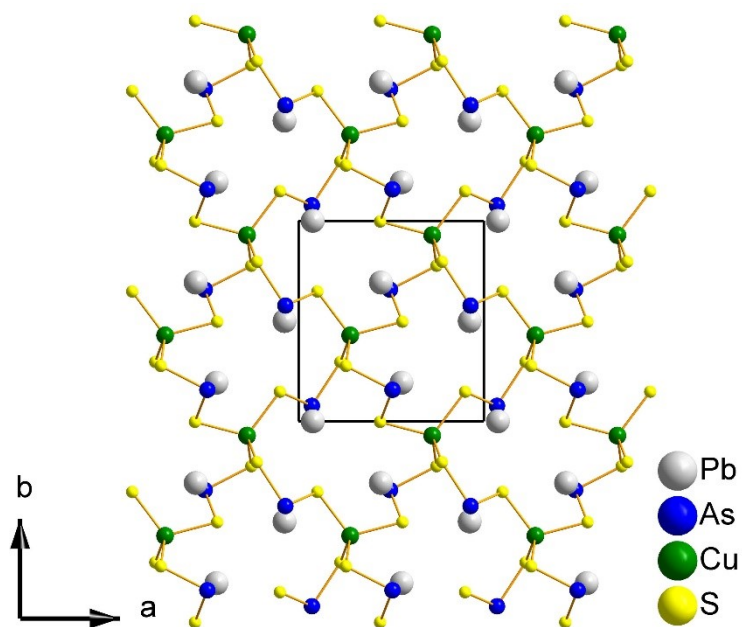


Figure S10. 3D structure of PbCuAsS_3 along the c direction.

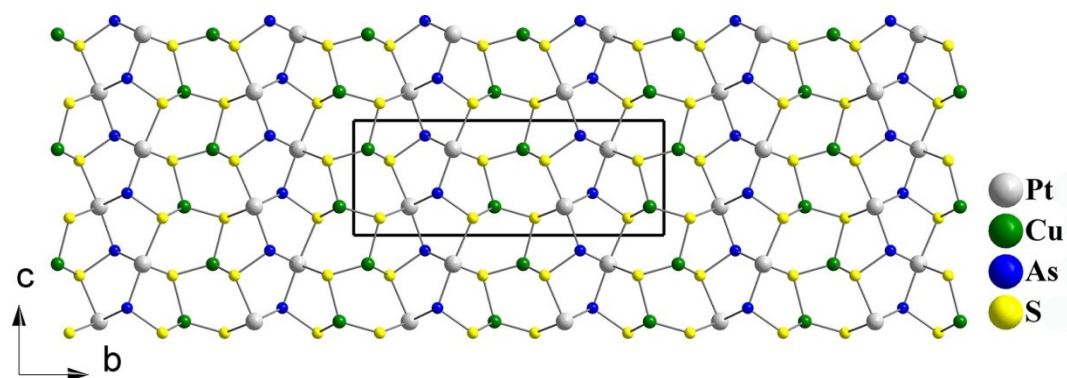


Figure S11. 3D structure of PtCuAsS₃ along the *a* direction.

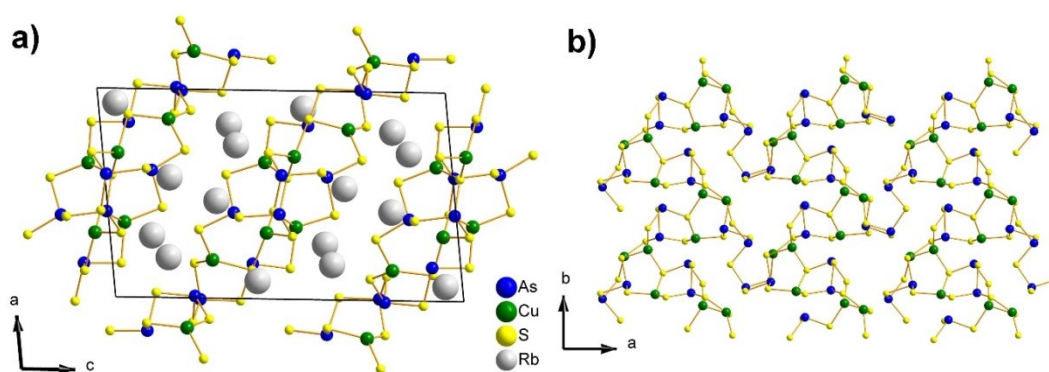


Figure S12. (a) 2D layered structure of Rb₈Cu₆As₈S₁₉ along the *b* direction. (b)

[Cu₆As₈S₁₉]⁸⁻ layer in the *ab* plane.

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Table S1. Selected bond lengths (Å) for Cs₃CuAs₄Q₈ (Q = S, Se).

Cs ₃ CuAs ₄ S ₈		Cs ₃ CuAs ₄ Se ₈	
Cu(1)-As(4)	2.6628(18)	Cu(1)-As(4)	2.615(2)
Cu(1)-S(4)	2.328(3)	Cu(1)-Se(4)	2.4414(15)
Cu(1)-S(5)	2.288(3)	Cu(1)-Se(5)	2.3908(16)
Cu(1)-S(8)	2.298(3)	Cu(1)-Se(8)	2.4136(14)
As(1)-S(2)	2.154(3)	As(1)-Se(2)	2.3039(15)
As(1)-S(3)	2.311(3)	As(1)-Se(3)	2.434(2)
As(1)-S(7)	2.313(3)	As(1)-Se(7)	2.4487(15)
As(2)-S(3)	2.252(3)	As(2)-Se(3)	2.3861(14)
As(2)-S(4)	2.189(3)	As(2)-Se(4)	2.3394(18)
As(2)-S(6)	2.289(3)	As(2)-Se(6)	2.4215(13)
As(3)-S(1)	2.299(3)	As(3)-Se(1)	2.4273(18)
As(3)-S(7)	2.264(3)	As(3)-Se(7)	2.4110(13)
As(3)-S(8)	2.201(3)	As(3)-Se(8)	2.3537(13)
As(4)-S(1)	2.280(3)	As(4)-Se(1)	2.4148(13)
As(4)-S(5)	2.179(3)	As(4)-Se(5)	2.3322(14)
As(4)-S(6)	2.318(3)	As(4)-Se(6)	2.4454(15)
Cs(1)-S(2)	3.513(3)	Cs(1)-Se(2)	3.6485(13)
Cs(1)-S(5)	3.849(3)	Cs(1)-Se(7)	4.3085(13)
Cs(1)-S(6)	3.924(3)	Cs(1)-Se(6)	3.9442(18)
Cs(2)-S(1)	3.688(3)	Cs(2)-Se(1)	3.7381(16)
Cs(2)-S(1)	3.690(3)	Cs(2)-Se(1)	3.7595(15)
Cs(2)-S(1)	4.079(3)	Cs(2)-Se(1)	4.326(2)
Cs(2)-S(2)	3.504(3)	Cs(2)-Se(2)	3.606(2)
Cs(2)-S(2)	3.880(3)	Cs(2)-Se(2)	3.9250(15)
Cs(2)-S(5)	4.159(3)	Cs(2)-Se(5)	4.328(2)

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Cs(2)-S(6)	3.636(3)	Cs(2)-Se(6)	3.7384(12)
Cs(2)-S(7)	3.711(3)	Cs(2)-Se(7)	3.9400(14)
Cs(2)-S(7)	3.896(3)	Cs(2)-Se(7)	3.935(2)
Cs(2)-S(8)	3.617(3)	Cs(2)-Se(8)	3.6504(18)
Cs(3)-S(2)	3.477(4)	Cs(3)-Se(2)	3.6005(19)
Cs(3)-S(3)	4.075(3)	Cs(3)-Se(3)	3.7215(12)
Cs(3)-S(3)	3.631(3)	Cs(3)-Se(3)	4.1309(15)
Cs(3)-S(4)	3.885(3)	Cs(3)-Se(4)	3.7162(13)
Cs(3)-S(4)	3.537(3)	Cs(3)-Se(4)	3.9687(16)
Cs(3)-S(8)	3.547(3)	Cs(3)-Se(8)	3.5847(12)
Cs(3)-S(8)	3.506(2)	Cs(3)-Se(8)	3.6184(19)
Cs(3)-S(7)	4.148(3)	Cs(3)-Se(7)	4.341(2)
Cs(4)-S(4)	3.527(3)	Cs(4)-Se(4)	3.6124(11)
Cs(4)-S(5)	3.524(3)	Cs(4)-Se(5)	3.6488(13)
Cs(4)-S(6)	3.583(3)	Cs(4)-Se(6)	3.6866(17)
Cs(4)-S(8)	3.688(3)	Cs(4)-Se(8)	3.8163(11)

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Table S2. Selected Bond Angles (deg) for Cs₃CuAs₄Q₈ (Q = S, Se).

Cs ₃ CuAs ₄ S ₈		Cs ₃ CuAs ₄ Se ₈	
S(1)-As(4)-S(6)	93.11(11)	Se(1)-As(4)-Se(6)	93.01(5)
S(2)-As(1)-S(3)	99.16(12)	Se(2)-As(1)-Se(3)	98.73(6)
S(2)-As(1)-S(7)	102.99(11)	Se(2)-As(1)-Se(7)	103.37(5)
S(3)-As(1)-S(7)	98.92(12)	Se(3)-As(1)-Se(7)	98.80(6)
S(3)-As(2)-S(6)	98.27(11)	Se(3)-As(2)-Se(6)	97.46(5)
S(4)-As(2)-S(3)	100.14(11)	Se(4)-As(2)-Se(3)	99.45(5)
S(4)-As(2)-S(6)	106.14(11)	Se(4)-As(2)-Se(6)	107.82(6)
S(5)-As(4)-S(1)	104.32(11)	Se(5)-As(4)-Se(1)	103.78(5)
S(5)-As(4)-S(6)	102.93(10)	Se(5)-As(4)-Se(6)	102.46(6)
S(7)-As(3)-S(1)	96.36(11)	Se(7)-As(3)-Se(1)	96.31(6)
S(8)-As(3)-S(1)	101.75(10)	Se(8)-As(3)-Se(1)	101.29(5)
S(8)-As(3)-S(7)	100.64(11)	Se(8)-As(3)-Se(7)	101.24(5)
S(1)-As(4)-Cu(1)	100.25(8)	Se(1)-As(4)-Cu(1)	100.97(5)
S(5)-As(4)-Cu(1)	124.94(9)	Se(5)-As(4)-Cu(1)	125.30(5)
S(6)-As(4)-Cu(1)	124.12(9)	Se(6)-As(4)-Cu(1)	124.07(6)
S(5)-Cu(1)-S(4)	115.04(11)	Se(5)-Cu(1)-Se(4)	116.95(6)
S(5)-Cu(1)-S(8)	121.42(11)	Se(5)-Cu(1)-Se(8)	116.81(6)
S(8)-Cu(1)-S(4)	115.36(11)	Se(8)-Cu(1)-Se(4)	115.45(5)
S(4)-Cu(1)-As(4)	89.66(9)	Se(4)-Cu(1)-As(4)	88.69(6)
S(5)-Cu(1)-As(4)	119.66(8)	Se(5)-Cu(1)-As(4)	122.28(6)
S(8)-Cu(1)-As(4)	88.31(9)	Se(8)-Cu(1)-As(4)	91.15(6)

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Table S3. Structural features of selected quaternary X/Cu/As/Q (X = inorganic cations; Q = chalcogen) system.

Compounds	Cu/As ratio	Crystal system	Space group	Structural dimension	Ref.
VCu ₁₃ As ₃ S ₁₆	4.33	Cubic	$P\bar{4}3n$	3D	1
KCu ₄ AsS ₄	4.0	Monoclinic	$P2_1$	3D	2
RbCu ₄ AsS ₄	4.0	Monoclinic	$P2_1$	3D	2
KCu ₂ AsS ₃	2.0	Triclinic	$P\bar{1}$	2D	2
RbCu ₂ AsS ₃	2.0	Monoclinic	$P2_1/c$	2D	2
CsCu ₂ AsS ₃	2.0	Orthorhombic	$Pbca$	2D	3
Hg ₃ Cu ₆ As ₄ S ₁₂	1.5	Trigonal	$R\bar{3}$	3D	4
PbCuAsS ₃	1.0	Orthorhombic	$Pmn2_1$	3D	5
PtCuAsS ₃	1.0	Monoclinic	Cc	3D	6
Rb ₈ Cu ₆ As ₈ S ₁₉	0.75	Monoclinic	$P2_1$	2D	7
Cs₃CuAs₄S₈	0.25	Monoclinic	$P2_1/c$ (14)	2D	This work
Cs₃CuAs₄Se₈	0.25	Monoclinic	$P2_1/c$ (14)	2D	This work

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